

### High Power Thyristor Hockey Puk Version S/SS-PUK Series 5500PS/PSS

Types : 5500 PS/PSS

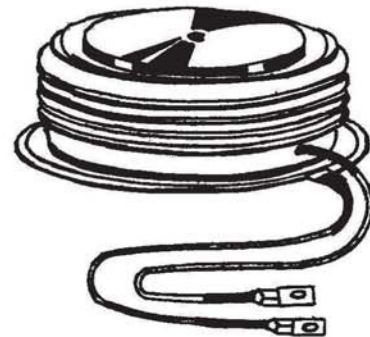
#### FEATURES

- ❖ Center amplifying gate.
- ❖ Metal case with ceramic insulator
- ❖ High profile hockey - puk.

#### TYPICAL APPLICATIONS

- ❖ DC motor control (e.g. for machine tools).
- ❖ Controlled rectifiers (e.g. for battery charging, Uninterrupted Power Supply).
- ❖ AC controllers (e.g. for temperature control, lights control).

5500 (S/SS-PUK)



#### Major Ratings and Characteristics

| Parameter         | 5500PS/PSS   | Units             |
|-------------------|--------------|-------------------|
| $I_{T(AV)}$       | 5500         | A                 |
| @ $T_{hs}$        | 70           | °C                |
| $I_{T(RMS)}$      | 8635         | A                 |
| @ $T_{hs}$        | 70           | °C                |
| $I_{TSM}$ @ 50 Hz | 75           | KA                |
| $I^2t$ @ 50 Hz    | 28125        | KA <sup>2</sup> s |
| $V_{DRM}/V_{RRM}$ | 1600 to 3600 | V                 |
| $t_q$ typical     | 400          | μs                |
| $T_J$             | 125          | °C                |

## SILICON CONTROLLED RECTIFIERS

### ELECTRICAL SPECIFICATIONS

#### 5500PS/PSS Series

#### Voltage Ratings

| Type number | Voltage Code | $V_{DRM}/V_{RRM}$ , max repetitive peak and off-state voltage<br>V | $V_{RSM}$ , maximum non-repetitive peak voltage<br>V | $I_{DRM}/I_{RRM}$ max.<br>@ $T_J = T_J$ max.<br>mA |
|-------------|--------------|--------------------------------------------------------------------|------------------------------------------------------|----------------------------------------------------|
| 5500PS/PSS  | 160          | 1600 / 1600                                                        | 1700                                                 | 400                                                |
|             | 200          | 2000 / 2000                                                        | 2100                                                 |                                                    |
|             | 260          | 2600 / 2600                                                        | 2700                                                 |                                                    |
|             | 360          | 3600 / 3600                                                        | 3700                                                 |                                                    |

#### On - state Conduction

| Parameter                                                           | 5500PS/PSS | Units             | Conditions                                                           |
|---------------------------------------------------------------------|------------|-------------------|----------------------------------------------------------------------|
| $I_{T(AV)}$ Max. average on-state current<br>@ Heatsink temperature | 5500       | A                 | 180° conduction, half sine wave<br>double side cooled                |
|                                                                     | 70         | °C                |                                                                      |
| $I_{T(RMS)}$ Max RMS on-state current                               | 8635       | A                 | DC @ 70°C heatsink temperature double side cooled                    |
| $I_{TSM}$ Max. peak, one-cycle non-repetitive surge current         | 75         | KA                | $t = 10$ ms<br><br>Sinusoidal half wave,<br>Initial $T_J = T_J$ max. |
| $I^2t$ Maximum $I^2t$ for fusing                                    | 28125      | KA <sup>2</sup> s | $t = 10$ ms                                                          |
| $V_{T(TO)}$ Threshold voltage                                       | 0.86       | V                 | $T_J = T_J$ max                                                      |
| $r_t$ On-state slope resistance                                     | 0.073      | mΩ                | $T_J = T_J$ max.                                                     |
| $V_{TM}$ Max. on state voltage                                      | 1.3        | V                 | $I_{PK} = 4000A, T_J = T_J$ max, $t_p = 10$ ms sine pulse            |
| $I_H$ Maximum holding current                                       | 600        | mA                | $T_J = 25^\circ\text{C}$ , anode supply 12 V resistive load          |
| $I_L$ Typical latching current                                      | 1000       | mA                | $T_J = 25^\circ\text{C}$ , anode supply 12 V resistive load          |

## SILICON CONTROLLED RECTIFIERS

### Switching

#### 5500PS/PSS Series

| Parameter                                                      | 5500PS/PSS | Units | Conditions                                                                                                               |
|----------------------------------------------------------------|------------|-------|--------------------------------------------------------------------------------------------------------------------------|
| di/dt<br>Max. non-repetitive rate of rise of turned-on current | 300        | A/μs  | Gate drive 20V, 20Ω, $t_r \leq 1\mu s$<br>$T_J = T_J$ max. anode voltage $\leq 80\% V_{DRM}$                             |
| $t_q$<br>Typical turn-off time                                 | 400        | μs    | $I_{TM} = 1000A$ , $T_J = T_J$ max. di/dt = 5 A/μs, $V_R = 100V$<br>dv/dt = 20V/μs, $V_{DRM} = 2000V$ , $t_p = 500\mu s$ |

### Blocking

| Parameter                                                                 | 5500PS/PSS | Units | Conditions                                           |
|---------------------------------------------------------------------------|------------|-------|------------------------------------------------------|
| dv/dt<br>Maximum critical rate of rise of off-state voltage               | 1000       | V/μs  | $T_J = T_J$ max. linear to 67% rated $V_{DRM}$       |
| $I_{RRM}$<br>$I_{DRM}$<br>Max. peak reverse and off-state leakage current | 400        | mA    | $T_J = T_J$ max. rated $V_{DRM}$ / $V_{RRM}$ applied |

### Triggering

| Parameter                                       | 5500PS/PSS | Units | Conditions                                                                                                                                                       |
|-------------------------------------------------|------------|-------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| $P_{GM}$<br>Maximum peak gate power             | 50         | W     | $T_J = T_J$ max., $t_p \leq 5$ ms                                                                                                                                |
| $P_{G(AV)}$<br>Maximum average gate power       | 5          |       | $T_J = T_J$ max., $f = 50Hz$ , $d\% = 50$                                                                                                                        |
| $I_{GM}$<br>Max. peak positive gate current     | 3.0        | A     | $T_J = T_J$ max., $t_p \leq 5$ ms                                                                                                                                |
| $+V_{GM}$<br>Maximum peak positive gate voltage | 20         | V     | $T_J = T_J$ max., $t_p \leq 5$ ms                                                                                                                                |
| $-V_{GM}$<br>Maximum peak negative gate voltage | 5.0        |       |                                                                                                                                                                  |
| $I_{GT}$<br>DC gate current required to trigger | MAX.       | mA    | $T_J = 25^\circ C$<br><br>Max.required gate trigger/ current/voltage are the lowest value which will trigger all units 12 V anode-to-cathode applied             |
|                                                 | 300        |       |                                                                                                                                                                  |
| $V_{GT}$<br>DC gate voltage required to trigger | 5.0        | V     | $T_J = 25^\circ C$                                                                                                                                               |
| $I_{GD}$<br>DC gate current not to trigger      | 15         | mA    | $T_J = T_J$ max.<br><br>Max. gate current/voltage not to trigger is the max. value which will not trigger any unit with rated $V_{DRM}$ anode-to-cathode applied |
| $V_{GD}$<br>DC gate voltage not to trigger      | 0.25       | V     |                                                                                                                                                                  |

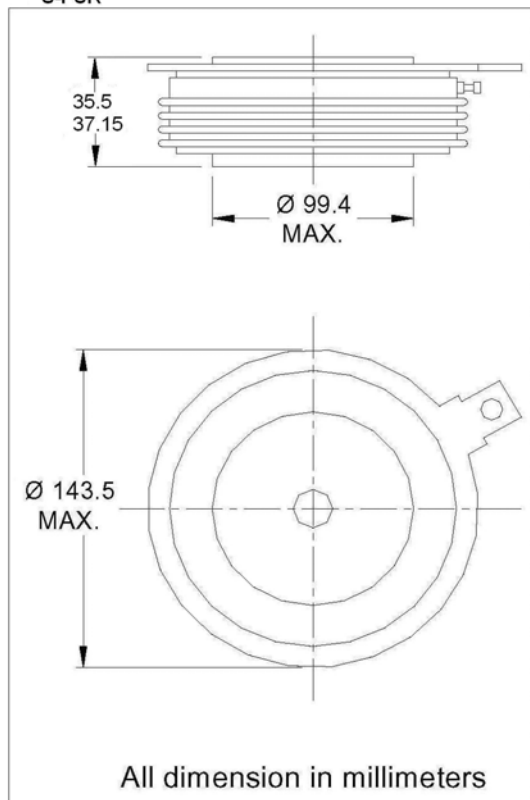
# SILICON CONTROLLED RECTIFIERS

## 5500PS/PSS Series

### Thermal and Mechanical Specifications

| Parameter                                             | 5500PS/PSS | Units | Conditions                      |
|-------------------------------------------------------|------------|-------|---------------------------------|
| $T_J$ Max. operating temperature range                | 125        | °C    |                                 |
| $T_{stg}$ Max. storage temperature range              | 150        |       |                                 |
| $R_{thJ-C}$ Max. thermal resistance, junction to case | 0.008      | K/W   | DC operation double side cooled |
| F Mounting force, $\pm 10\%$                          | 80 to 90   | KN    |                                 |
| wt. Approximate weight                                | 3000       | g     |                                 |
| Case style                                            | S/SS-PUK   |       | See Outline Table               |

S-PUK



SS-PUK

